

## LISTING OF THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in this application. Added text is indicated by underlining, and deleted text is indicated by ~~strike through~~. Changes are identified by a vertical bar in the margin.

1. (Previously presented) A cluster resonator, comprising:
  - a first conducting plane;
  - a second substantially parallel conducting plane;
  - a cluster of vias of essentially uniform length oriented substantially normal to the conducting planes, each via in the cluster comprising a first end and a second end;
    - a first conducting pad disposed in a third plane substantially parallel and capacitively coupled to the first conducting plane and physically coupled with the vias of the cluster of vias proximate their first ends; and
    - a second conducting pad disposed in a fourth plane substantially parallel and capacitively coupled to the second conducting plane and physically coupled with the vias of the cluster of vias proximate their second ends, wherein the vias are physically connected to only the first and second conducting pads.
2. (Previously presented) The cluster resonator of claim 1, wherein a combined inductance and capacitance of the cluster of vias form an electromagnetically resonant shunt circuit between the first and second conducting planes.

3. (Original) The cluster resonator of claim 2, wherein the vias of the cluster of vias are disposed along a perimeter that defines an interior region.

4. (Original) The cluster resonator of claim 3, wherein one or more interior vias are routed within the interior region of the cluster of vias.

5. (Currently amended) The cluster resonator of claim 4, wherein the interior vias comprise portions of transmission lines passing electrical signals ~~vertically~~ through the cluster resonator.

6. (Original) The cluster resonator of claim 1, wherein the first conducting pad is external relative to the first and second conducting planes.

7. (Original) The cluster resonator of claim 1, wherein the first conducting pad is internal relative to the first and second conducting planes.

8. (Original) The cluster resonator of claim 1, wherein the second conducting pad is external relative to the first and second conducting planes.

9. (Original) The cluster resonator of claim 1, wherein the second conducting pad is internal relative to the first and second conducting planes.

10. (Original) The cluster resonator of claim 1, wherein the first and second conducting pads are internal relative to the first and second conducting planes.

11. (Original) The cluster resonator of claim 1, wherein the first and second conducting pads are external relative to the first and second conducting planes.

12. (Previously presented) The cluster resonator of claim 1, wherein its topology comprises a mechanically balanced structure.

13. (Previously presented) The cluster resonator of claim 1, wherein the first and second conducting planes are metallic layers incorporated with a multi-layered panel circuit.

14. (Currently amended) The cluster resonator of claim 13, wherein the ~~first and second conducting planes are metallic layers incorporated within a~~ multi-layered panel circuit is a multi-layered printed circuit board and the cluster resonator comprises an array of plated through holes.

15. (Currently amended) The cluster resonator of claim 13, wherein the ~~first and second conducting planes are metallic layers incorporated within~~ multi-layered panel circuit is a multi-chip module.

16. (Currently amended) The cluster resonator of claim 13, wherein the ~~first and second conducting planes are metallic layers incorporated within~~ multi-layered panel circuit is a semiconductor chip.

17. (Original) The cluster resonator of claim 3, wherein the cluster of vias is disposed along a circular path.

18. (Original) The cluster resonator of claim 3, wherein the cluster of vias is disposed along an elliptical path.

19. (Original) The cluster resonator of claim 3, wherein the cluster of vias is disposed along a polygonal path.

20. (Previously presented) The cluster resonator of claim 4, wherein spacing of vias within the cluster of vias effects a Faraday cage that substantially shields the interior region from RF fields propagating within the first and second conducting planes.

21. (Previously presented) The cluster resonator of claim 20, wherein spacing of the vias within the cluster of vias in relation to the interior vias effects a predetermined line impedance in the interior vias.

22. (Currently amended) A cluster resonator, comprising:

- a first conducting plane;
- a second substantially parallel conducting plane;
- a cluster of vias of essentially uniform length oriented substantially normal to the conducting planes, each via in the cluster comprising a first end and a second end;
- first ends of each via in the cluster of vias coupled with the first conducting plane; and
- a first conducting pad disposed in a third plane parallel and external to the region between the first and second conducting plane-planes and

~~capacitely~~ capacitively coupled to the second conducting plane ~~thereto and~~ physically coupled to each via in the cluster of vias proximate their second ends, wherein the vias in the cluster of vias are physically connected to only the first conducting plane and the first conducting pad.

23. (Previously presented) The cluster resonator of claim 22, wherein a combined inductance and capacitance of the cluster of vias form an electromagnetically resonant shunt circuit between the first and second conducting planes.

24. (Previously presented) The cluster resonator of claim 22, wherein the vias of the cluster of vias are disposed along a perimeter that defines an interior region.

25. (Original) The cluster resonator of claim 24, wherein one or more interior vias are routed within the internal region of the cluster of vias.

26. (Currently amended) The cluster resonator of claim ~~24~~25, wherein the interior vias comprise portions of transmission lines passing electrical signals ~~vertically~~ through the resonant element.

27. (Canceled)

28. (Canceled)

29. (Currently amended) The cluster resonator of claim 22 comprising a second cluster of vias, each via in the second cluster of vias

comprising a first end and a second end, wherein the vias in the second cluster of vias are coupled proximate their first ends to the second conducting plane and proximate their second ends to a second conducting pad disposed in a fourth plane parallel and external to the region between the first and second conducting plane-planes and ~~capacitely-capacitively~~ coupled to the first conducting plane, wherein the vias in the cluster of vias are physically connected to only the second conducting plane and the second conducting pad.

30. (Canceled)

31. (Currently amended) The cluster resonator of ~~claim 22~~claims 29 and 30, wherein its topology comprises a mechanically balanced structure.

32. (Previously presented) The cluster resonator of claim 22, wherein the first and second conducting planes are metallic layers incorporated with a multi-layered panel circuit.

33. (Currently amended) The cluster resonator of claim 32, wherein the ~~first and second conducting planes are metallic layers incorporated within~~multi-layered panel circuit is a multi-layered printed circuit board and the cluster resonator comprises an array of plated through holes.

34. (Currently amended) The cluster resonator of claim 22, wherein the ~~first and second conducting planes are metallic layers incorporated within~~multi-layered panel circuit is a multi-chip module.

35. (Currently amended) The cluster resonator of claim 22, wherein the ~~first and second conducting planes are metallic layers incorporated within~~multi-layered panel circuit is a semiconductor chip.

36. (Original) The cluster resonator of claim 24, wherein the cluster of vias is disposed along a circular path.

37. (Original) The cluster resonator of claim 24, wherein the cluster of vias is disposed along an elliptical path.

38. (Original) The cluster resonator of claim 24 wherein the cluster of vias is disposed along a polygonal path.

39. (Currently amended) The cluster resonator of claim ~~24~~25, wherein spacing of the vias of the cluster of vias ~~effect~~effects a Faraday cage that substantially shields the interior region from RF fields propagating within the first and second conducting planes.

40. (Currently amended) The cluster resonator of claim 39, wherein spacing of the vias of the cluster of vias in relation to the interior vias ~~effect~~effects a predetermined line impedance in the interior vias.

41. (Canceled)

42. (New) The cluster resonator of claim 1, further comprising a plurality of resonant vias and associated first and second conducting pads disposed in a periodic array associated with the first and second conducting planes.

43. (New) The cluster resonator of claim 22, further comprising a plurality of resonant vias and associated first conducting pads disposed in a periodic array associated with the first and second conducting planes.

44. (New) An apparatus for suppressing electromagnetic interference comprising:

a first conducting pad;

a second substantially parallel conducting pad; and

a cluster of vias of essentially uniform length disposed between and oriented substantially normal to the conducting pads, each via of the cluster of vias having a first end and a second end, wherein the first and second ends are physically connected respectively to the first and second conducting pads;

wherein the vias of the cluster of vias are disposed along a perimeter thereby forming a substantially field free interior region therewithin; and

wherein one or more electrically isolated interior vias traverse the interior region of the cluster of vias, the interior vias comprising portions of transmission lines for passing electrical signals therethrough.



45. (New) The apparatus of claim 44 wherein a spacing of the vias of the cluster of vias in relation to the interior vias is selected to effect a predetermined line impedance in the interior vias.

46. (New) The apparatus of claim 44, wherein a diameter of the vias of the cluster of vias is selected to effect a predetermined inductance.

47 (New) The cluster resonator of claim 1, wherein a diameter of the vias of the cluster of vias is selected to effect a predetermined inductance.

48. (New) The cluster resonator of claim 22, wherein a diameter of the vias of the cluster of vias is selected to effect a predetermined inductance.

49. (New) The apparatus of claim 44, wherein the cluster of vias is disposed along a circular path.

50. (New) The apparatus of claim 44, wherein the cluster of vias is disposed along an elliptical path.

51. (New) The apparatus of claim 44 wherein the cluster of vias is disposed along a polygonal path.

52. (New) The apparatus of claim 44, wherein the first and second conducting pads are metallic layers incorporated within a multi-layered panel circuit.

53. (New) The apparatus of claim 52, wherein the multi-layered panel circuit is a multi-layered printed circuit board and the cluster resonator comprises an array of plated through holes.

54. (New) The apparatus of claim 52, wherein the multi-layered panel circuit is a multi-chip module.

55. (New) The apparatus of claim 52, wherein the multi-layered panel circuit is a semiconductor chip.

56. (New) An apparatus for suppressing electromagnetic radiation comprising:

- a first conducting plane;
- a first substantially parallel conducting pad;
- a cluster of vias oriented substantially normal to the first conducting plane and first conducting pad and disposed therebetween, each via of the cluster having a first end and a second end, wherein the first and second ends are physically connected respectively to the first conducting plane and first conducting pad;

- wherein the vias of the cluster of vias are disposed along a perimeter thereby forming a substantially field free interior region therewithin; and

- wherein one or more electrically isolated interior vias traverse the interior region of the cluster of vias, the interior vias comprising portions of transmission lines for passing electrical signals therethrough.

57. (New) The apparatus of claim 56 wherein a spacing of the vias of the cluster of vias in relation to the interior vias is selected to effect a predetermined line impedance in the interior vias.

58. (New) The apparatus of claim 56, wherein a diameter of the vias of the cluster of vias is selected to effect a predetermined inductance.

59. (New) The apparatus of claim 56, wherein the cluster of vias is disposed along a circular path.

60. (New) The apparatus of claim 56, wherein the cluster of vias is disposed along an elliptical path.

61. (New) The apparatus of claim 56 wherein the cluster of vias is disposed along a polygonal path.

62. (New) The apparatus of claim 56, wherein the first conducting plane and first conducting pad are metallic layers incorporated within a multi-layered panel circuit.

63. (New) The apparatus of claim 62, wherein the multi-layered panel circuit is a multi-layered printed circuit board and the cluster resonator comprises an array of plated through holes.

64. (New) The apparatus of claim 62, wherein the multi-layered panel circuit is a multi-chip module.

65. (New) The apparatus of claim 62, wherein the multi-layered panel circuit is a semiconductor chip.

66. (New) The apparatus of claim 56 further comprising a second conducting plane substantially parallel to the first conducting plane wherein the first conducting pad is external to the region between the first and second conducting planes and capacitively coupled to the second conducting plane.

67. (New) The apparatus of claim 56 further comprising a second conducting plane substantially parallel to the first conducting plane wherein the first conducting pad is internal to the region between the first and second conducting planes and capacitively coupled to the second conducting plane.

68. (New) A cluster resonator comprising:

- a first conducting plane;
- a second substantially parallel conducting plane;
- a first conducting pad disposed in a third substantially parallel plane internal to the region between the first and second conducting planes;
- a first cluster of vias oriented substantially normal to the first conducting plane and first conducting pad and disposed therebetween, each via of the cluster having a first end and a second end, wherein the first and second ends are physically connected respectively to the first conducting plane and first conducting pad; and
- a second conducting pad disposed in a fourth substantially parallel plane internal to the region between the first and second conducting planes;

a second cluster of vias oriented substantially normal to the second conducting plane and second conducting pad and disposed therebetween, each via of the cluster having a first end and a second end, wherein the first and second ends are physically connected respectively to the second conducting plane and second conducting pad; and

wherein the first and second conducting pads are proximate and capacitively coupled to each other.

69. (New) The cluster resonator of claim 68, wherein the vias of the clusters of vias are disposed along a common perimeter thereby forming substantially field free interior regions therewithin; and

wherein one or more electrically isolated interior vias traverse the interior regions of the clusters of vias, the interior vias comprising portions of transmission lines for passing electrical signals therethrough.

70. (New) The cluster resonator of claim 69 wherein a spacing of the vias of the clusters of vias in relation to the interior vias is selected to effect a predetermined line impedance in the interior vias.

71. (New) The cluster resonator of claim 69, wherein a diameter of the vias of the clusters of vias is selected to effect a predetermined inductance.

72. (New) The cluster resonator of claim 69, wherein the common perimeter is circular.

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73. (New) The cluster resonator of claim 69, wherein the common perimeter is elliptical.

74. (New) The cluster resonator of claim 69 wherein the common perimeter is polygonal.

75. (New) The cluster resonator of claim 69, wherein the first and second conducting planes are metallic layers incorporated within a multi-layered panel circuit.

76. (New) The cluster resonator of claim 75, wherein the multi-layered panel circuit is a multi-layered printed circuit board and the cluster resonator comprises an array of plated through holes.

77. (New) The cluster resonator of claim 75, wherein the multi-layered panel circuit is a multi-chip module.

78. (New) The cluster resonator of claim 75, wherein the multi-layered panel circuit is a semiconductor chip.